

Notice of References CitedApplication/Control No.
09/838,892Applicant(s)/Patent Under Reexam
Chu et alExaminer
Savitri MulpuriArt Unit
2812

Page 1 of 1

U.S. PATENT DOCUMENTS

	Document Number Country Code-Number-Kind Code	Date MM-YYYY ¹	Name	Classification ²	
A	6,190,975	2/01	Kubo et al	438	285
B	2001/0160605	10/02	Kanazawa et al	438	689
C	5,683,934	11/97	Candelaria et al	438	----
D					
E					
F					
G					
H					
I					
J					
K					
L					
M					

FOREIGN PATENT DOCUMENTS

	Document Number Country Code-Number-Kind Code	Date MM-YYYY ¹	Country	Name	Classification ²	
N						
O						
P						
Q						
R						
S						
T						

NON-PATENT DOCUMENTS

	Include, as applicable: Author, Title, Date, Publisher, Edition or Volume, Pertinent Pages
U	Todd et al, "growth of heteroepitaxial SiGeC alloys on silicon using novel chemistry.", Appl. Phys. Lett. 67 9(1) 28 August 1995
V	
W	
X	

¹ A copy of this reference is not being furnished with this Office action. See MPEP § 707.05(a).¹ Dates in MM-YYYY format are publication dates.² Classifications may be U.S. or foreign.